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# 150 mA, Tri-Mode, LDO Linear Voltage Regulator

The NCP4587 is a CMOS 150 mA LDO which switches to a low power mode under light current loads. The device automatically switches back to a fast response mode as the output load increases above 3 mA (typ.) or it can be placed in permanent fast mode through a mode select pin. The family is available in a variety of packages: SC-70, SOT23 and an ultra thin (0.4 mm) small 1.2 x 1.2 mm XDFN.

#### **Features**

- Operating Input Voltage Range: 1.4 V to 5.25 V
- Output Voltage Range: 0.8 to 4.0 V (Available in 0.1 V steps)
- Supply current: Low Power Mode  $-1.0~\mu A$  Fast Mode  $-55~\mu A$  Standby Mode  $-0.1~\mu A$
- Very Low Dropout: 120 mV Typ. at 150 mA ( $V_{out} > 2.6 \text{ V}$ )
- $\pm 1\%$  Output Voltage Accuracy (V<sub>OUT</sub> > 2 V, T<sub>J</sub> = 25°C)
- High PSRR: 70 dB at 1 kHz (Fast response mode)
- Line Regulation 0.02%/V Typ.
- Current Fold Back Protection
- Stable with Ceramic Capacitors
- Available in 1.2 x 1.2 XDFN, SC-70 and SOT23 Package
- These are Pb-Free Devices

#### **Typical Applications**

- Battery Powered Equipments
- Portable Communication Equipments
- Cameras, Image Sensors and Camcorders

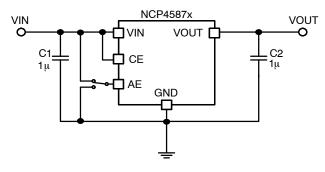
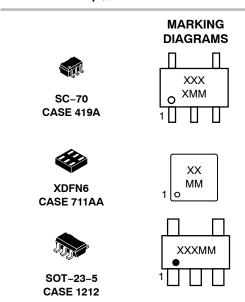


Figure 1. Typical Application Schematic



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#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 16 of this data sheet.

XX, XXX= Specific Device Code MM = Date Code

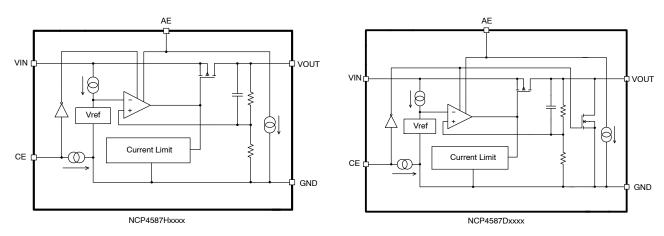


Figure 2. Simplified Schematic Block Diagram

#### PIN FUNCTION DESCRIPTION

| Pin No.<br>XDFN | Pin No.<br>SC-70 | Pin No.<br>SOT23 | Pin Name | Description                  |  |
|-----------------|------------------|------------------|----------|------------------------------|--|
| 4               | 4                | 1                | VIN      | Input pin                    |  |
| 2               | 2                | 2                | GND      | Ground                       |  |
| 3               | 5                | 3                | CE       | Chip enable pin (active "H") |  |
| 6               | 3                | 5                | VOUT     | Output pin                   |  |
| 1               | 1                | 4                | AE       | Auto Eco Pin                 |  |
| 5               | =                | -                | NC       | No connection                |  |

#### **ABSOLUTE MAXIMUM RATINGS**

| Rating                                    | Symbol             | Value             | Unit |
|---|--------------------|-------------------|------|
| Input Voltage (Note 1)                    | V <sub>IN</sub>    | 6.0               | V    |
| Output Voltage                            | Vouт               | -0.3 to Vin + 0.3 | V    |
| Chip Enable Input                         | Vce                | -0.3 to 6.0       | V    |
| Auto Eco Input                            | V <sub>AE</sub>    | -0.3 to 6.0       | V    |
| Output Current                            | I <sub>OUT</sub>   | 400               | mA   |
| Power Dissipation XDFN                    | P <sub>D</sub>     | 400               | mW   |
| Power Dissipation SC-70                   |                    | 380               |      |
| Power Dissipation SOT23                   |                    | 420               |      |
| Maximum Junction Temperature              | $T_{J(MAX)}$       | 150               | °C   |
| Storage Temperature                       | T <sub>STG</sub>   | -55 to 125        | °C   |
| Operation Temperature                     | T <sub>A</sub>     | -40 to 85         | °C   |
| ESD Capability, Human Body Model (Note 2) | ESD <sub>HBM</sub> | 2000              | V    |
| ESD Capability, Machine Model (Note 2)    | ESD <sub>MM</sub>  | 200               | V    |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection and is tested by the following methods:

- ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
- ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
- Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

#### THERMAL CHARACTERISTICS

| Rating   | Symbol         | Value | Unit |
|--|----------------|-------|------|
| Thermal Characteristics, XDFN Thermal Resistance, Junction-to-Air  | $R_{	heta JA}$ | 250   | °C/W |
| Thermal Characteristics, SOT23 Thermal Resistance, Junction-to-Air | $R_{	hetaJA}$  | 238   | °C/W |
| Thermal Characteristics, SC-70 Thermal Resistance, Junction-to-Air | $R_{	heta JA}$ | 263   | °C/W |

#### **ELECTRICAL CHARACTERISTICS**

 $-40^{\circ}C \le T_A \le 85^{\circ}C$ ;  $V_{IN} = V_{OUT(NOM)} + 1$  V or 2.5 V, whichever is greater;  $I_{OUT} = 1$  mA,  $C_{IN} = C_{OUT} = 0.47$   $\mu$ F, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .

| Parameter                           | Test Cor   | Symbol                                       | Min                 | Тур    | Max  | Unit     |        |
|-------------------------------------|--|--|---------------------|--------|------|----------|--------|
| Operating Input Voltage             |  |  | Vin                 | 1.4    |      | 5.25     | V      |
| Output Voltage                      | TA = +25 °C,   | V <sub>OUT</sub> > 2 V                       | Vоит                | x0.99  |      | x1.01    | V      |
|                                     | I <sub>OUT</sub> = 5 mA  | V <sub>OUT</sub> ≤ 2 V                       |                     | -20    |      | 20       | mV     |
|                                     | -40°C ≤ T <sub>A</sub> ≤ 85°C,   | V <sub>OUT</sub> > 2 V                       | 1                   | x0.975 |      | x1.015   | V      |
|                                     | I <sub>OUT</sub> = 5 mA  | V <sub>OUT</sub> ≤ 2 V                       | 1                   | -50    |      | 30       | mV     |
| Output Voltage Temp.<br>Coefficient | $T_A = -40$  | to 85°C                                      |                     |        | ±50  |          | ppm/°C |
| Line Regulation                     | $V_{IN} = V_{OUT} + 0.5 \text{ V to}$<br>5 V, $V_{IN} \ge 1.4 \text{ V}$ | I <sub>OUT</sub> = 1 mA,<br>(Low Power Mode) | Line <sub>Reg</sub> |        |      | 0.50     | %/V    |
|                                     |  | I <sub>OUT</sub> = 10 mA,<br>(Fast Mode)     |                     |        | 0.02 | 0.20     |        |
| Load Regulation                     | IOUT = 1 mA to 10 mA   | V <sub>OUT</sub> > 2.0 V                     | Line <sub>Reg</sub> | -1.0   |      | 1.0      | %      |
|                                     |  | V <sub>OUT</sub> ≤ 2.0 V                     |                     | -20    |      | 20       | mV     |
|                                     | Iout = 10 m/   |  |                     | 18     | 40   | mV       |        |
| Dropout Voltage                     | l <sub>OUT</sub> = 150 mA  | 0.8 V ≤ V <sub>OUT</sub> < 0.9 V             | VDO                 |        |      | (Note 3) | V      |
|                                     |  | 0.9 V ≤ V <sub>OUT</sub> < 1.0 V             |                     |        |      | (Note 3) |        |
|                                     |  | 1.0 V ≤ V <sub>OUT</sub> < 1.5 V             | 1                   |        | 0.24 | 0.4      |        |
|                                     |  | 1.5 V ≤ V <sub>OUT</sub> < 2.6 V             |                     |        | 0.19 | 0.25     |        |
|                                     |  | 2.6 V ≤ V <sub>OUT</sub> < 4.0 V             |                     |        | 0.12 | 0.18     |        |
| Output Current                      |  |  | Іоит                | 150    |      |          | mA     |
| Short Current Limit                 | V <sub>OUT</sub>   | = 0 V  | I <sub>SC</sub>     |        | 50   |          | mA     |
| Quiescent Current                   | IOUT = 0 mA,<br>Low Power Mode<br>(Note 4)                               | V <sub>OUT</sub> ≤ 1.85 V                    | ΙQ                  |        | 1.0  | 4.0      | μΑ     |
|                                     |  | V <sub>OUT</sub> > 1.85 V                    |                     |        | 1.5  | 4.0      |        |
| Supply Current                      | I <sub>OUT</sub> = 10 m/   | A, Fast Mode                                 | I <sub>GND</sub>    |        | 55   |          | μΑ     |
| Standby Current                     | V <sub>CE</sub> = 0 V,   | T <sub>J</sub> = 25°C                        | Isтв                |        | 0.1  | 1        | μΑ     |
| Fast Mode Switch-Over Current       | I <sub>OUT</sub> = light to heavy load                                   |  | Іоитн               |        |      | 8.0      | mA     |
| Low Power Switch-Over<br>Current    | I <sub>OUT</sub> = heavy   | to light load                                | I <sub>OUTL</sub>   | 1.0    | 2.0  |          | mA     |
| CE Pin Threshold Voltage            | CE Input Voltage "H" CE Input Voltage "L"                                |  | VCEH                | 1.0    |      |          | V      |
|                                     |  |  | VCEL                |        |      | 0.4      | 1      |
| CE Pull Down Current                |  |  | ICEPD               |        | 0.1  |          | μΑ     |

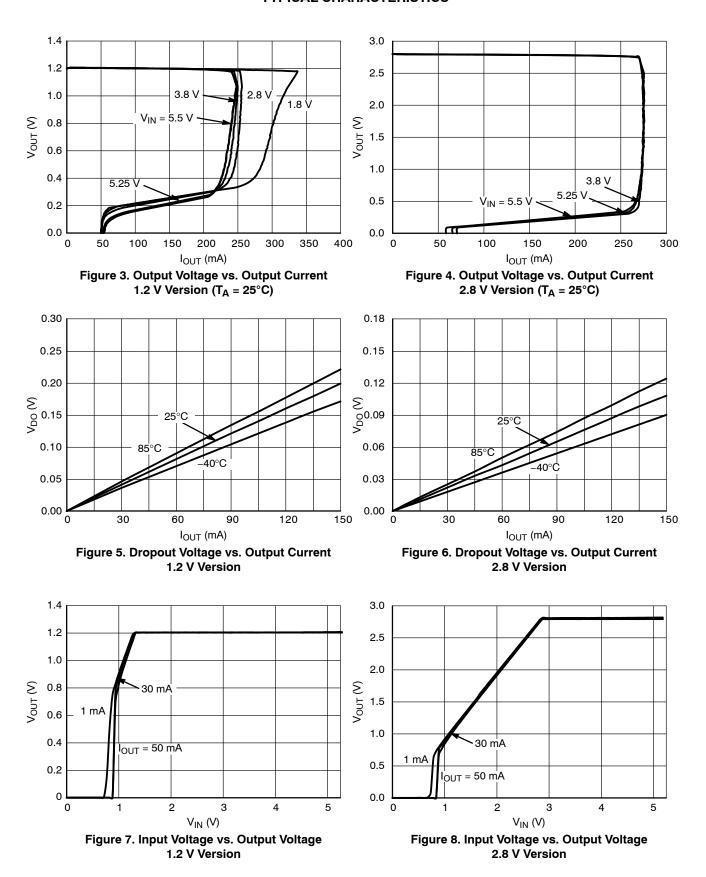
 <sup>3.</sup> V<sub>IN</sub> > 1.4 V condition is dominant against this specification
 4. The value of quiescent current is excluding the pull-down current of CE and AE pin

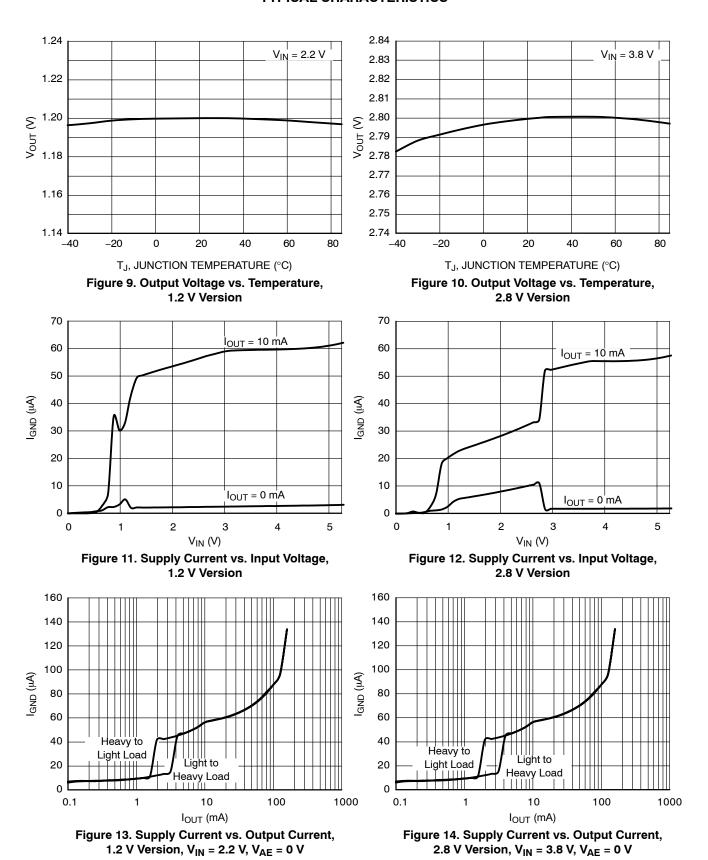
## **ELECTRICAL CHARACTERISTICS**

 $-40^{\circ}C \leq T_{A} \leq 85^{\circ}C; \ V_{IN} = V_{OUT(NOM)} + 1 \ V \ or \ 2.5 \ V, \ whichever \ is \ greater; \ I_{OUT} = 1 \ mA, \ C_{IN} = C_{OUT} = 0.47 \ \mu F, \ unless \ otherwise \ noted.$  Typical values are at  $T_{A} = +25^{\circ}C$ .

| Parameter                           | Test Conditions   | Symbol           | Min | Тур | Max | Unit          |
|-------------------------------------|---|------------------|-----|-----|-----|---------------|
| AE Pin Threshold Voltage            | AE Input Voltage "H"  | VAEH             | 1.0 |     |     | V             |
|                                     | AE Input Voltage "L"  | VAEL             |     |     | 0.4 | 1             |
| AE Pull Down Current                |   | IAEPD            |     | 0.1 |     | μΑ            |
| Power Supply Rejection Ratio        | $\begin{aligned} &V_{IN} = V_{OUT} + 1 \text{ V or } 2.2 \text{ V whichever is higher,} \\ &\Delta V_{IN} = 0.2 \text{ V}_{pk-pk}, \text{ IOUT} = 30 \text{ mA, f} = 1 \text{ kHz, Fast} \\ &\text{Mode} \end{aligned}$ | PSRR             |     | 70  |     | dB            |
| Output Noise Voltage                | V <sub>OUT</sub> = 1.2 V, I <sub>OUT</sub> = 30 mA, f = 10 Hz to<br>100 kHz   | V <sub>N</sub>   |     | 115 |     | $\mu V_{rms}$ |
| Low Output Nch Tr. On<br>Resistance | V <sub>IN</sub> = 4 V, V <sub>CE</sub> = 0 V  | R <sub>LOW</sub> |     | 50  |     | Ω             |

 <sup>3.</sup> V<sub>IN</sub> > 1.4 V condition is dominant against this specification
 4. The value of quiescent current is excluding the pull-down current of CE and AE pin





#### **TYPICAL CHARACTERISTICS**

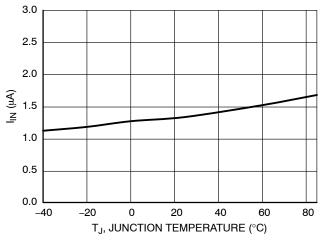


Figure 15. Supply Current vs. Temperature, 1.2 Version, V<sub>IN</sub> = 2.2 V, V<sub>AE</sub> = 0 V

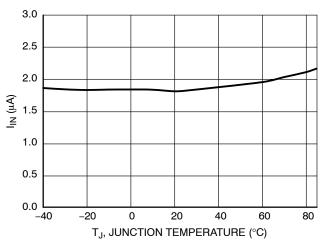


Figure 16. Supply Current vs. Temperature, 2.8 Version, V<sub>IN</sub> = 3.8 V, V<sub>AE</sub> = 0 V

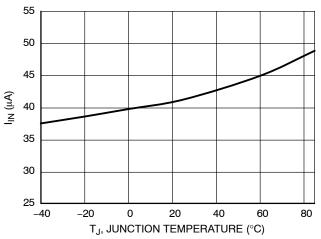


Figure 17. Supply Current vs. Temperature, 1.2 Version,  $V_{IN}$  = 2.2 V,  $V_{AE}$  = 2.2 V

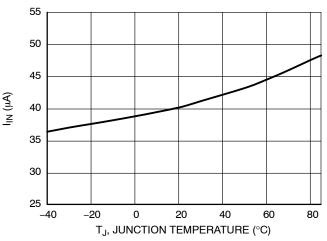


Figure 18. Supply Current vs. Temperature, 2.8 Version,  $V_{IN}$  = 3.8 V,  $V_{AE}$  = 3.8 V

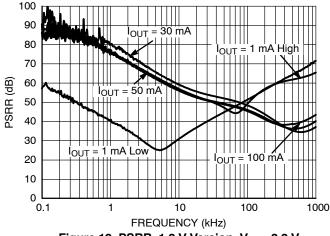


Figure 19. PSRR, 1.2 V Version, V<sub>IN</sub> = 2.2 V

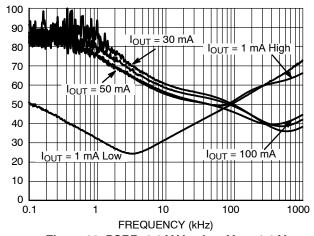
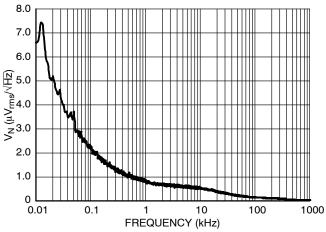


Figure 20. PSRR, 2.8 V Version, V<sub>IN</sub> = 3.8 V

PSRR (dB)



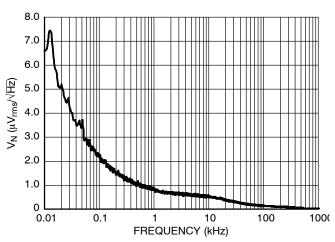


Figure 22. Output Voltage Noise, 2.8 V Version,  $I_{OUT}$  = 30 mA,  $V_{IN}$  = 3.8 V

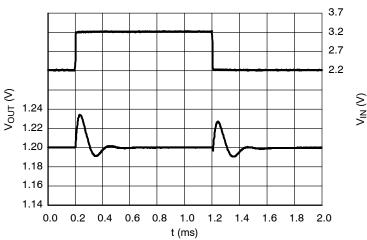


Figure 23. Line Transients, 1.2 V Version,  $t_R$  =  $t_F$  = 5  $\mu s,\, I_{OUT}$  = 1 mA, AE = 0 V

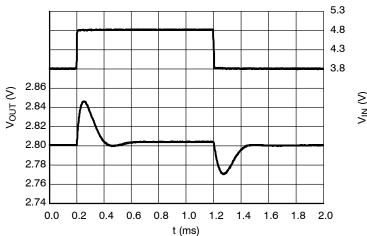


Figure 24. Line Transients, 2.8 V Version,  $t_R = t_F = 5 \mu s$ ,  $l_{OUT} = 1 \mu A$ , AE = 0 V

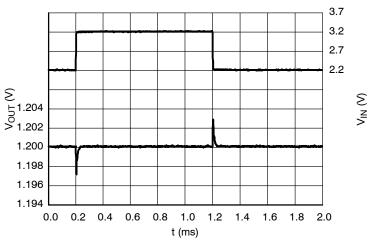


Figure 25. Line Transients, 1.2 V Version,  $t_R$  =  $t_F$  = 5  $\mu s,\, I_{OUT}$  = 30 mA, AE =  $V_{IN}\, V$ 

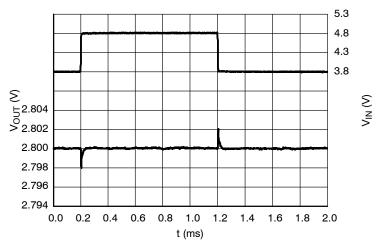


Figure 26. Line Transients, 2.8 V Version,  $t_{R}$  =  $t_{F}$  = 5  $\mu s,\,l_{OUT}$  = 30 mA, AE =  $V_{IN}\,V$ 

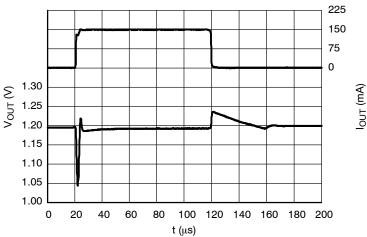


Figure 27. Load Transients, 1.2 V Version,  $I_{OUT}$  = 1 – 150 mA,  $t_R$  =  $t_F$  = 0.5  $\mu$ s,  $V_{IN}$  = 2.2 V, AE = 0 V

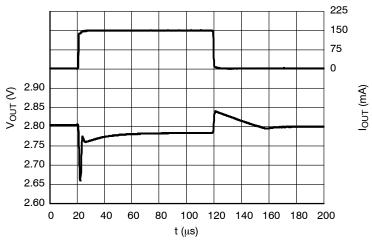


Figure 28. Load Transients, 2.8 V Version,  $I_{OUT}$  = 1 - 150 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s, \, V_{IN}$  = 2.2 V, AE = 0 V

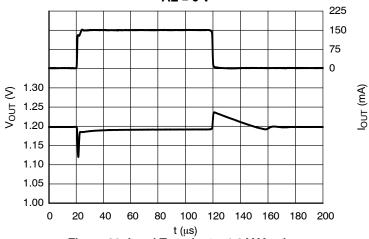


Figure 29. Load Transients, 1.2 V Version,  $I_{OUT}$  = 1 – 150 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s$ ,  $V_{IN}$  = 2.2 V, AE =  $V_{IN}$  V

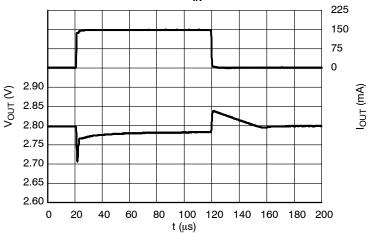


Figure 30. Load Transients, 2.8 V Version,  $I_{OUT}$  = 1 – 150 mA,  $t_R$  =  $t_F$  = 0.5  $\mu$ s,  $V_{IN}$  = 2.8 V, AE =  $V_{IN}$  V

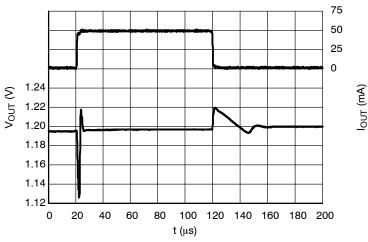


Figure 31. Load Transients, 1.2 V Version,  $I_{OUT}$  = 1 - 50 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s,\ V_{IN}$  = 2.2 V, AE = 0 V

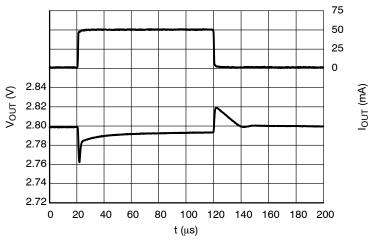


Figure 32. Load Transients, 2.8 V Version,  $I_{OUT}$  = 1 - 50 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s, \, V_{IN}$  = 3.8 V,

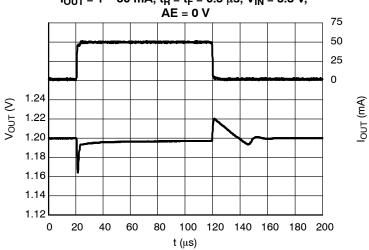


Figure 33. Load Transients, 1.2 V Version,  $I_{OUT}$  = 1 – 50 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s$ ,  $V_{IN}$  = 2.2 V, AE =  $V_{IN}$  V

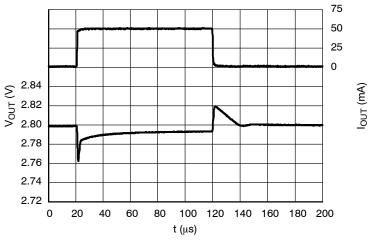


Figure 34. Load Transients, 2.8 V Version,  $I_{OUT}$  = 1 – 50 mA,  $t_R$  =  $t_F$  = 0.5  $\mu$ s,  $V_{IN}$  = 3.8 V, AE =  $V_{IN}$  V

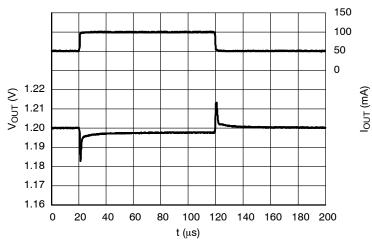


Figure 35. Load Transients, 1.2 V Version,  $I_{OUT}$  = 50 - 100 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s,\,V_{IN}$  = 2.2 V

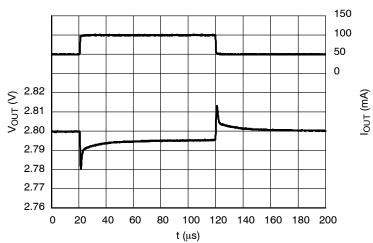


Figure 36. Load Transients, 2.8 V Version,  $I_{OUT}$  = 50 - 100 mA,  $t_R$  =  $t_F$  = 0.5  $\mu s,\,V_{IN}$  = 3.8 V

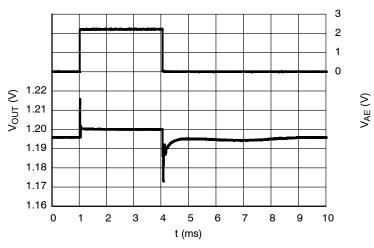


Figure 37. AE Switch Transients, 1.2 V Version,  $V_{IN}$  = 2.2 V,  $I_{OUT}$  = 1 mA

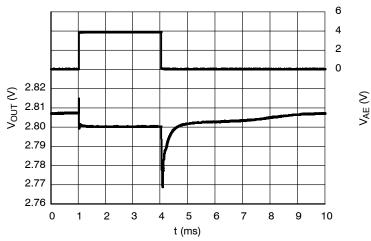


Figure 38. AE Switch Transients, 2.8 V Version,  $V_{\text{IN}}$  = 3.8 V,  $I_{\text{OUT}}$  = 1 mA

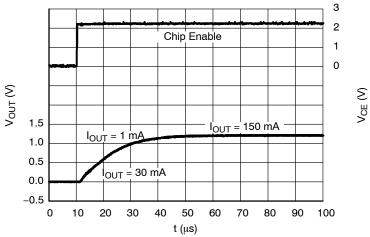


Figure 39. Start-up, 1.2 V Version,  $V_{IN}$  = 2.0 V

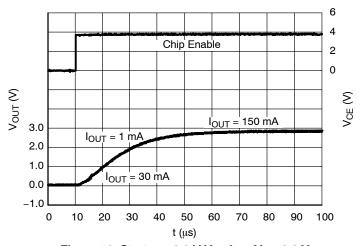


Figure 40. Start-up, 2.8 V Version,  $V_{\text{IN}}$  =3.8 V

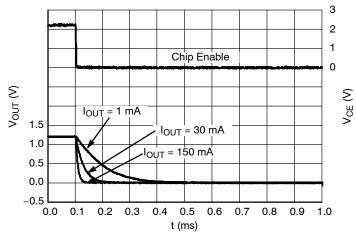


Figure 41. Shutdown, 1.2 V Version,  $V_{IN}$  = 2.2 V

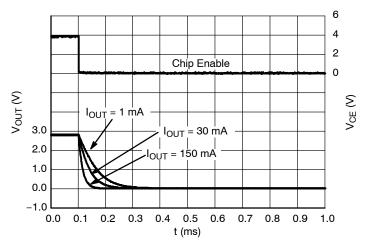


Figure 42. Shutdown, 2.8 V Version,  $V_{IN}$  = 3.8 V

#### APPLICATION INFORMATION

A typical application circuit for NCP4587 series is shown in Figure 43.

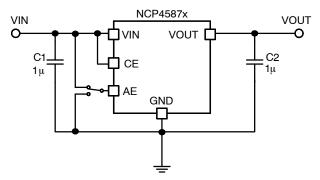


Figure 43. Typical Application Schematic

#### Input Decoupling Capacitor (C1)

A 1  $\mu F$  ceramic input decoupling capacitor should be connected as close as possible to the input and ground pin of the NCP4587. Higher values and lower ESR improves line transient response.

#### **Output Decoupling Capacitor (C2)**

A 1  $\mu F$  ceramic output decoupling capacitor is sufficient to achieve stable operation of the IC. If tantalum capacitor is used, and its ESR is high, the loop oscillation may result. If output capacitor is composed from few ceramic capacitors in parallel, the operation can be unstable. The capacitor should be connected as close as possible to the output and ground pin. Larger values and lower ESR improves dynamic parameters.

#### **Enable Operation**

Enable pin CE may be used for turning the regulator on and off. The regulator is switched on when CE pin voltage is above logic high level. Enable pin has internal pull down current source. If enable function is not needed connect CE pin to VIN.

#### **Current Limit**

This regulator includes fold-back type current limit circuit. This type of protection doesn't limit current up to

current capability in normal operation, but when over current occurs, the output voltage and current decrease until the over current condition ends. Typical characteristics of this protection type can be observed in the Output Voltage versus Output Current graphs shown in the typical characteristics chapter of this datasheet.

#### **Output Discharger**

The D version includes a transistor between VOUT and GND that is used for faster discharging of the output capacitor. This function is activated when the IC goes into disable mode.

#### **Auto ECO and Fast Mode**

The NCP4587 has two operation modes that have impact on supply current and transient response at low output current. These two modes can be selected by AE pin. If AE pin is at low level or floating Auto ECO mode is available. Please, see supply current vs. output current charts. If AE pin is at high level the device works in permanent Fast Transient Mode.

#### **Thermal**

As power across the IC increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and also the ambient temperature affect the rate of temperature rise for the part. That is to say, when the device has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

#### **PCB** layout

Make VIN and GND line sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect capacitors C1 and C2 as close as possible to the IC, and make wiring as short as possible.

#### **ORDERING INFORMATION**

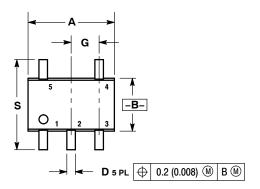
| Device          | Nominal Output<br>Voltage | Description    | Marking | Package             | Shipping <sup>†</sup> |
|-----------------|---------------------------|----------------|---------|---------------------|-----------------------|
| NCP4587DMX12TCG | 1.2 V                     | Auto discharge | YE      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DMX18TCG | 1.8 V                     | Auto discharge | YL      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DMX28TCG | 2.8 V                     | Auto discharge | YW      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DMX30TCG | 3.0 V                     | Auto discharge | YY      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DMX31TCG | 3.1 V                     | Auto discharge | YZ      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DMX33TCG | 3.3 V                     | Auto discharge | ZB      | XDFN<br>(Pb-Free)   | 5000 / Tape & Reel    |
| NCP4587DSN12T1G | 1.2 V                     | Auto discharge | DBE     | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| NCP4587DSN18T1G | 1.8 V                     | Auto discharge | DBL     | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| NCP4587DSN28T1G | 2.8 V                     | Auto discharge | DBW     | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| NCP4587DSN30T1G | 3.0 V                     | Auto discharge | DBY     | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| NCP4587DSN33T1G | 3.3 V                     | Auto discharge | EBB     | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |

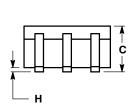
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

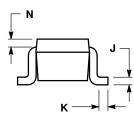
NOTE: To order other package and voltage variants, please contact your ON Semiconductor sales representative.

## **PACKAGE DIMENSIONS**

SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE K





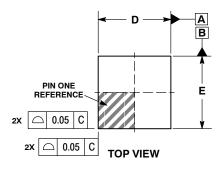


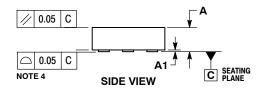
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

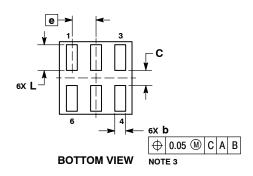
|     | INCHES        |       | MILLIN   | IETERS |
|-----|---------------|-------|----------|--------|
| DIM | MIN           | MAX   | MIN      | MAX    |
| Α   | 0.071         | 0.087 | 1.80     | 2.20   |
| В   | 0.045         | 0.053 | 1.15     | 1.35   |
| C   | 0.031         | 0.043 | 0.80     | 1.10   |
| D   | 0.004         | 0.012 | 0.10     | 0.30   |
| G   | 0.026         | BSC   | 0.65 BSC |        |
| Н   | · 0.          |       |          | 0.10   |
| J   | 0.004         | 0.010 | 0.10     | 0.25   |
| K   | 0.004         | 0.012 | 0.10     | 0.30   |
| N   | 0.008 REF     |       | 0.20     | REF    |
| S   | S 0.079 0.087 |       | 2.00     | 2.20   |

#### **PACKAGE DIMENSIONS**

#### XDFN6 1.2x1.2, 0.4P CASE 711AA-01 ISSUE O



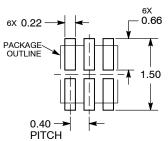




- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
- 2. CONTHOLLING DIMENSION: MILLIMETERS
  3. DIMENSION b APPLIES TO PLATED
  TERMINAL AND IS MEASURED BETWEEN
  0.15 AND 0.25mm FROM TERMINAL TIPS.
  4. COPLANARITY APPLIES TO ALL OF THE
  TERMINALS.

|     | MILLIMETERS |      |  |
|-----|-------------|------|--|
| DIM | MIN         | MAX  |  |
| Α   |             | 0.40 |  |
| A1  | 0.00        | 0.05 |  |
| b   | 0.13        | 0.23 |  |
| С   | 0.20        | 0.30 |  |
| D   | 1.20 BSC    |      |  |
| E   | 1.20 BSC    |      |  |
| е   | 0.40 BSC    |      |  |
| L   | 0.37        | 0.48 |  |

#### RECOMMENDED **MOUNTING FOOTPRINT\***

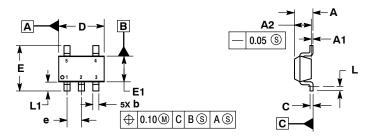


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

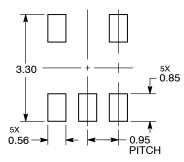
SOT-23 CASE 1212-01 **ISSUE A** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  CONTROLLING DIMENSIONS: MILLIMETERS.
- DATUM C IS THE SEATING PLANE

|     | MILLIMETERS |      |  |  |
|-----|-------------|------|--|--|
| DIM | MIN MAX     |      |  |  |
| Α   |             | 1.45 |  |  |
| A1  | 0.00        | 0.10 |  |  |
| A2  | 1.00        | 1.30 |  |  |
| b   | 0.30        | 0.50 |  |  |
| С   | 0.10        | 0.25 |  |  |
| D   | 2.70        | 3.10 |  |  |
| Е   | 2.50        | 3.10 |  |  |
| E1  | 1.50        | 1.80 |  |  |
| е   | 0.95        | BSC  |  |  |
| L   | 0.20        |      |  |  |
| L1  | 0.45        | 0.75 |  |  |

#### **RECOMMENDED** DERING FOOTPRINT\*



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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